

Complementary Silicon Power Transistors

D44VH10 (NPN), D45VH10 (PNP)

These complementary silicon power transistors are designed for high-speed switching applications, such as switching regulators and high frequency inverters. The devices are also well-suited for drivers for high power switching circuits.

Features

- Fast Switching
- Key Parameters Specified @ 100 °C
- Low Collector-Emitter Saturation Voltage
- Complementary Pairs Simplify Circuit Designs
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	80	Vdc
Collector-Emitter Voltage	V_{CEV}	100	Vdc
Emitter Base Voltage	V_{EB}	7.0	Vdc
Collector Current – Continuous	I_C	15	Adc
Collector Current – Peak (Note 1)	I_{CM}	20	Adc
Total Power Dissipation @ $T_C = 25\text{ °C}$ Derate above 25 °C	P_D	83 0.67	W W/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

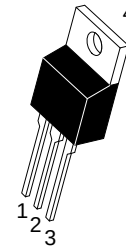
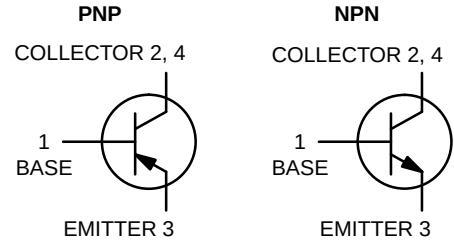
1. Pulse Width ≤ 6.0 ms, Duty Cycle $\leq 50\%$.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.5	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	T_L	275	°C

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

15 A COMPLEMENTARY SILICON POWER TRANSISTORS 80 V, 83 W



TO-220
CASE 221A
STYLE 1

MARKING DIAGRAM



x = 4 or 5
A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
D44VH10G	TO-220 (Pb-Free)	50 Units/Rail
D45VH10G	TO-220 (Pb-Free)	50 Units/Rail

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ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage (Note 2) ($I_C = 25\text{ mA}$, $I_B = 0$)	$V_{CEO(sus)}$	80	–	–	Vdc
Collector-Emitter Cutoff Current ($V_{CE} = \text{Rated } V_{CEV}$, $V_{BE(off)} = 4.0\text{ Vdc}$) ($V_{CE} = \text{Rated } V_{CEV}$, $V_{BE(off)} = 4.0\text{ Vdc}$, $T_C = 100\text{ }^{\circ}\text{C}$)	I_{CEV}	– –	– –	10 100	μAdc
Emitter Base Cutoff Current ($V_{EB} = 7.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	–	–	10	μAdc

ON CHARACTERISTICS (Note 2)

DC Current Gain ($I_C = 2.0\text{ Adc}$, $V_{CE} = 1.0\text{ Vdc}$) ($I_C = 4.0\text{ Adc}$, $V_{CE} = 1.0\text{ Vdc}$)	h_{FE}	35 20	– –	– –	–
Collector-Emitter Saturation Voltage ($I_C = 8.0\text{ Adc}$, $I_B = 0.4\text{ Adc}$) D44VH10 ($I_C = 8.0\text{ Adc}$, $I_B = 0.8\text{ Adc}$) D45VH10 ($I_C = 15\text{ Adc}$, $I_B = 3.0\text{ Adc}$, $T_C = 100\text{ }^{\circ}\text{C}$) D44VH10 D45VH10	$V_{CE(sat)}$	– – – –	– – – –	0.4 1.0 0.8 1.5	Vdc
Base-Emitter Saturation Voltage ($I_C = 8.0\text{ Adc}$, $I_B = 0.4\text{ Adc}$) D44VH10 ($I_C = 8.0\text{ Adc}$, $I_B = 0.8\text{ Adc}$) D45VH10 ($I_C = 8.0\text{ Adc}$, $I_B = 0.4\text{ Adc}$, $T_C = 100\text{ }^{\circ}\text{C}$) D44VH10 ($I_C = 8.0\text{ Adc}$, $I_B = 0.8\text{ Adc}$, $T_C = 100\text{ }^{\circ}\text{C}$) D45VH10	$V_{BE(sat)}$	– – – –	– – – –	1.2 1.0 1.1 1.5	Vdc

DYNAMIC CHARACTERISTICS

Current Gain Bandwidth Product ($I_C = 0.1\text{ Adc}$, $V_{CE} = 10\text{ Vdc}$, $f = 20\text{ MHz}$)	f_T	–	50	–	MHz
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_C = 0$, $f_{test} = 1.0\text{ MHz}$) D44VH10 D45VH10	C_{ob}	– –	120 275	– –	pF

SWITCHING CHARACTERISTICS

Delay Time	(V _{CC} = 20 Vdc, I _C = 8.0 Adc, I _{B1} = I _{B2} = 0.8 Adc)	t _d	–	–	50	ns
Rise Time		t _r	–	–	250	
Storage Time		t _s	–	–	700	
Fall Time		t _f	–	–	90	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2\%$.



D44VH10 (NPN), D45VH10 (PNP)

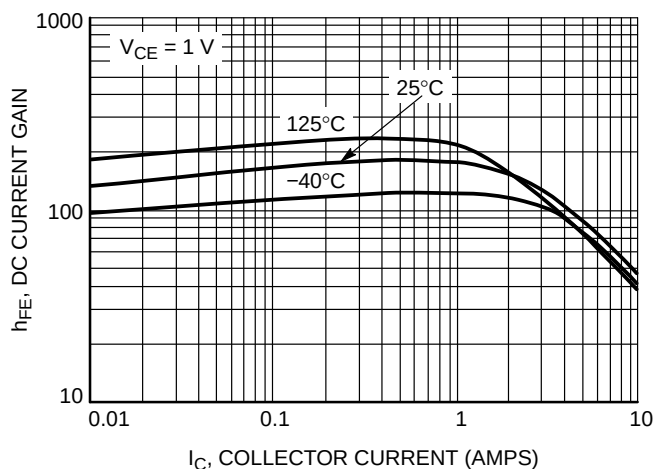


Figure 1. D44VH10 DC Current Gain

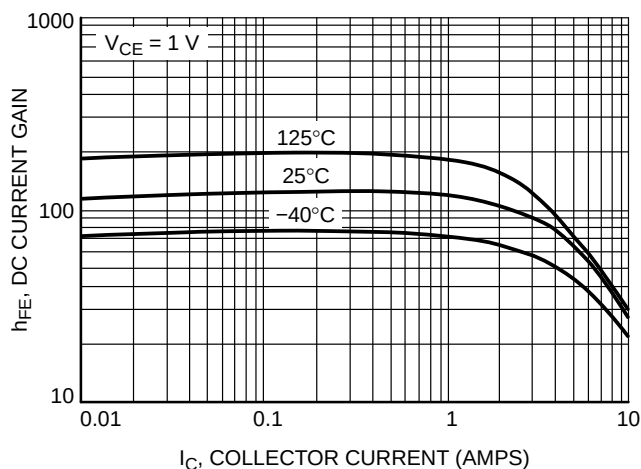


Figure 2. D45VH10 DC Current Gain

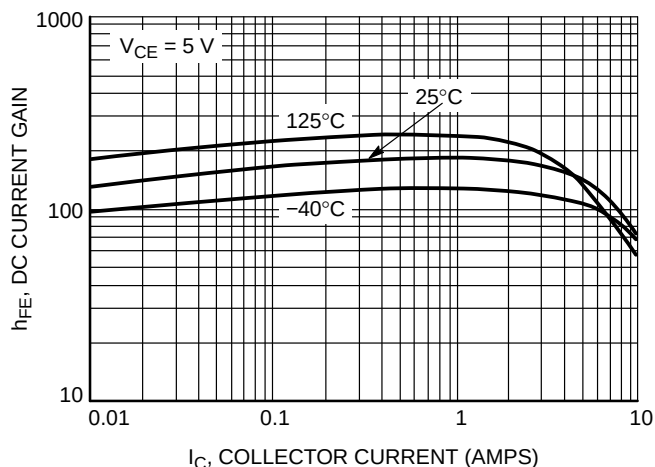


Figure 3. D44VH10 DC Current Gain

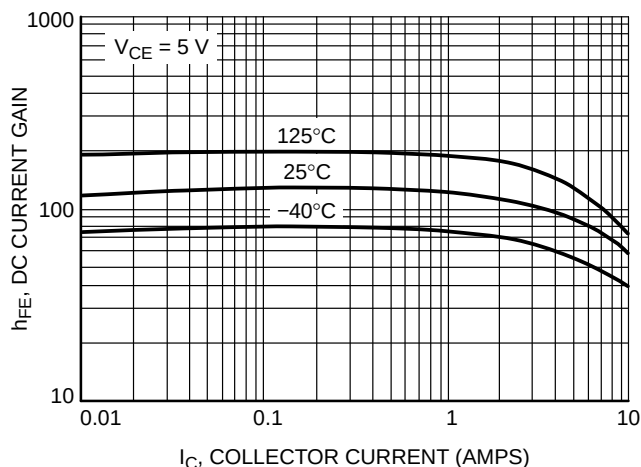


Figure 4. D45VH10 DC Current Gain

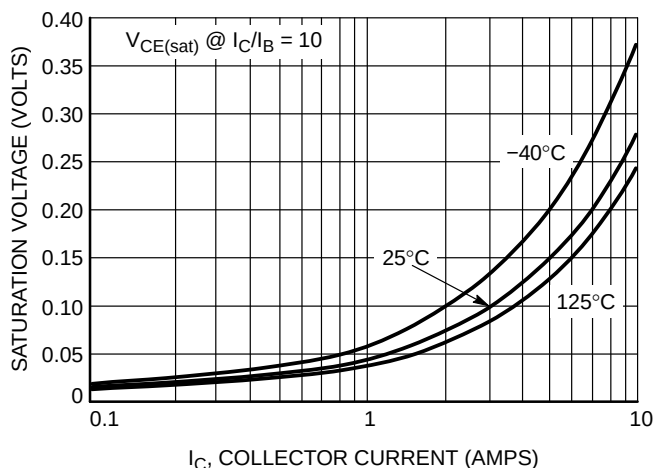


Figure 5. D44VH10 ON-Voltage

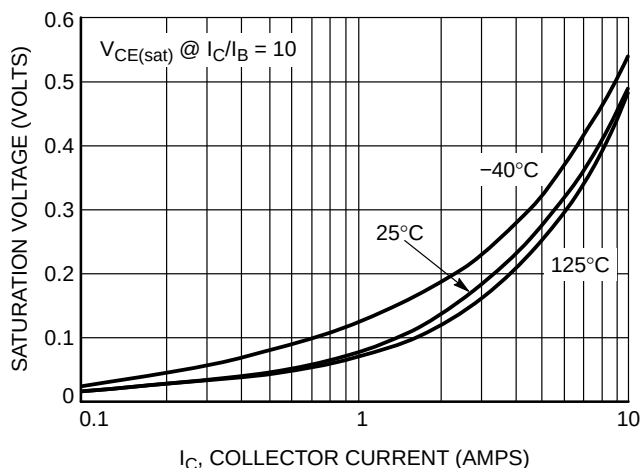


Figure 6. D45VH10 ON-Voltage

D44VH10 (NPN), D45VH10 (PNP)

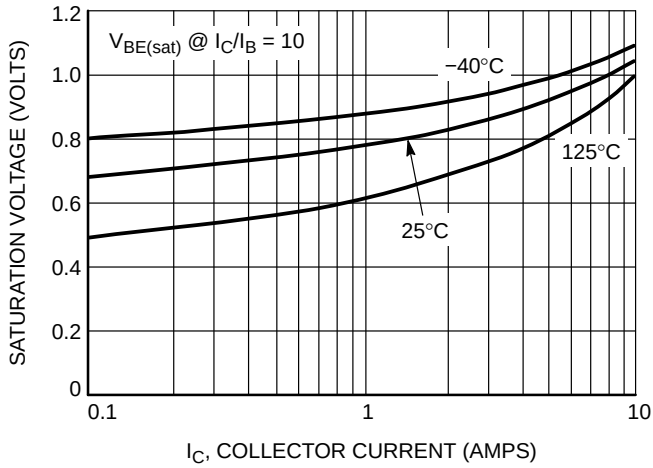


Figure 7. D44VH10 ON-Voltage

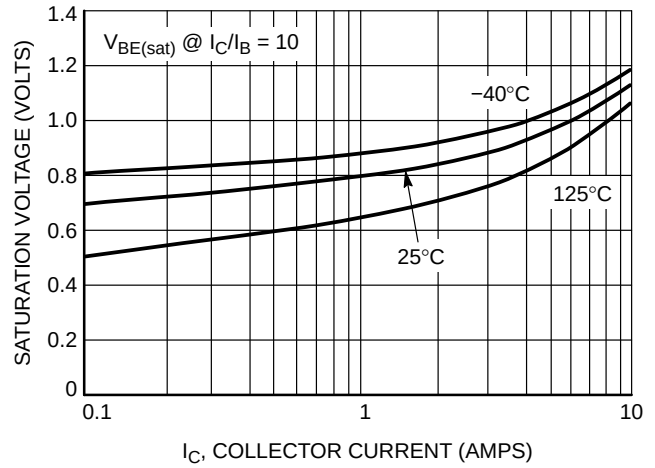


Figure 8. D45VH10 ON-Voltage

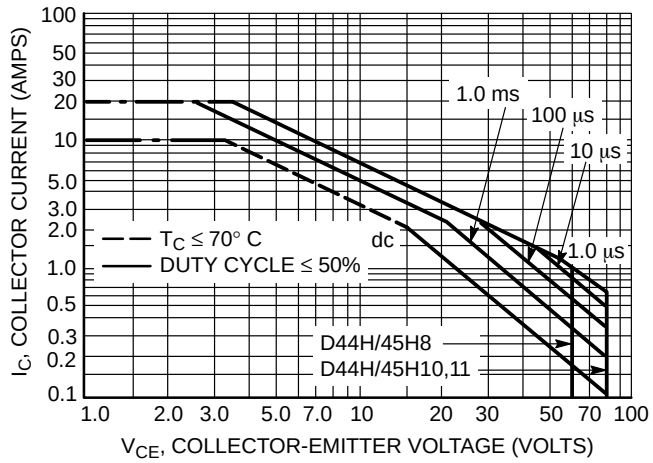


Figure 9. Maximum Rated Forward Bias Safe Operating Area

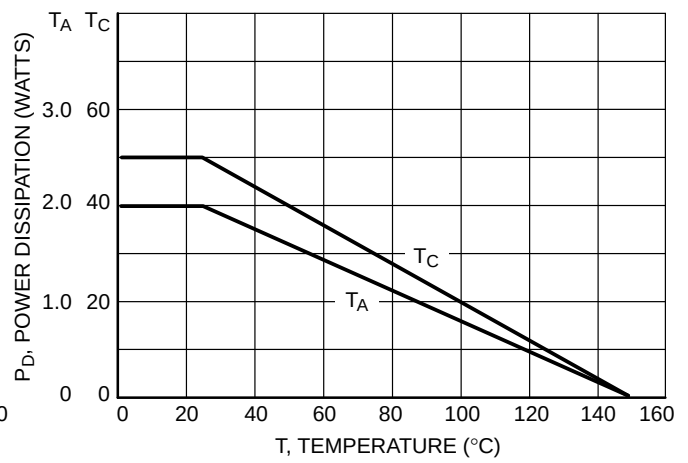


Figure 10. Power Derating

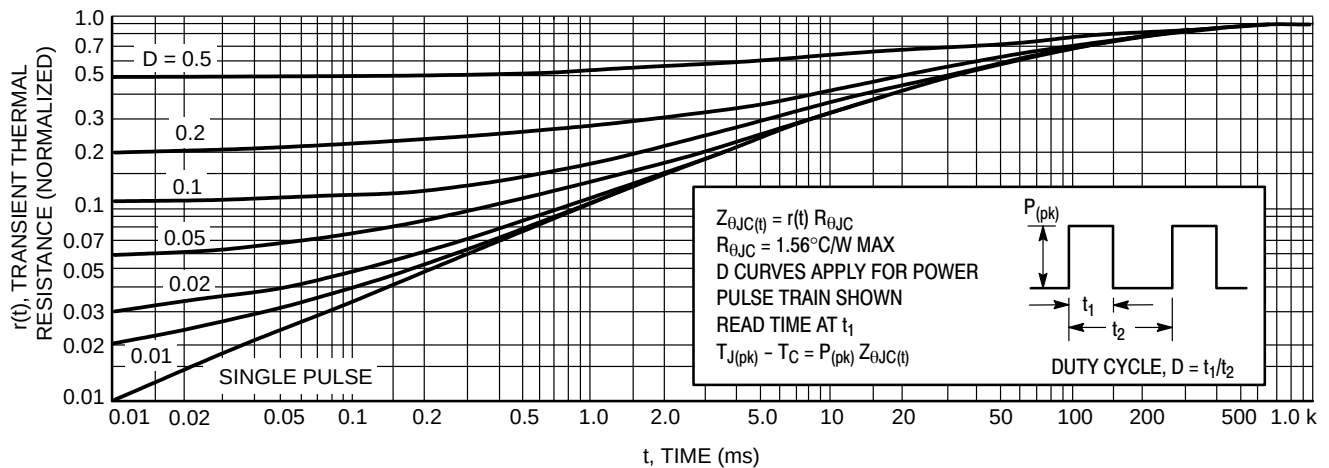
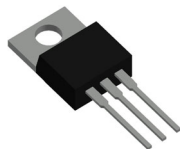


Figure 11. Thermal Response

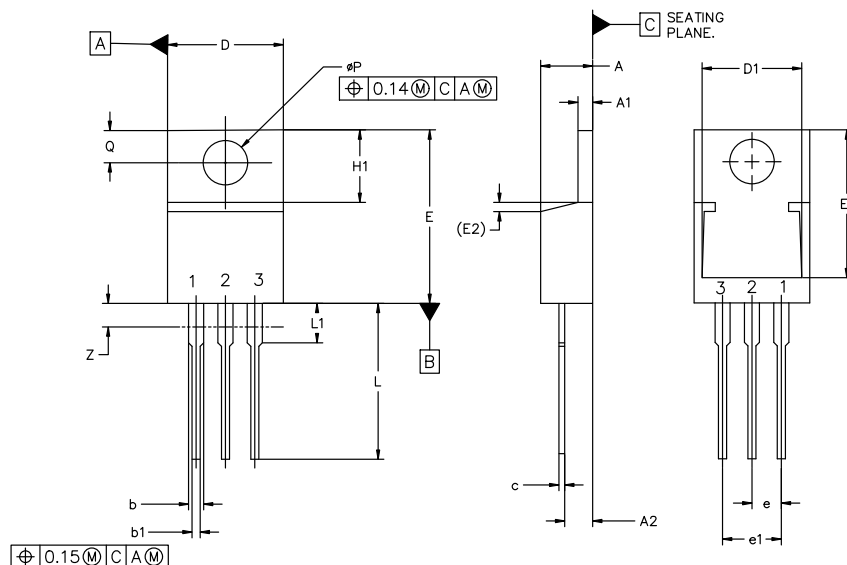


TO-220-3 10.10x15.12x4.45, 2.54P

CASE 221A

ISSUE AL

DATE 05 FEB 2025



MILLIMETERS			
DIM	MIN	NOM	MAX
A	4.07	4.45	4.83
A1	1.15	1.28	1.41
A2	2.04	2.42	2.79
b	1.15	1.34	1.52
b1	0.64	0.80	0.96
c	0.36	0.49	0.61
D	9.66	10.10	10.53
D1	8.43	8.63	8.83
E	14.48	15.12	15.75
E1	12.58	12.78	12.98
E2	1.27 REF		

MILLIMETERS			
DIM	MIN	NOM	MAX
e	2.42	2.54	2.66
e1	4.83	5.08	5.33
H1	5.97	6.22	6.47
L	12.70	13.49	14.27
L1	2.80	3.45	4.10
Q	2.54	2.79	3.04
øP	3.60	3.85	4.09
Z	---	---	3.48

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 2:
PIN 1. BASE
2. EMITTER
3. COLLECTOR
4. EMITTER

STYLE 3:
PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE

STYLE 4:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. MAIN TERMINAL 2

STYLE 5:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

STYLE 6:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. CATHODE

STYLE 7:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. ANODE

STYLE 8:
PIN 1. CATHODE
2. ANODE
3. EXTERNAL TRIP/DELAY
4. ANODE

STYLE 9:
PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 10:
PIN 1. GATE
2. SOURCE
3. DRAIN
4. SOURCE

STYLE 11:
PIN 1. DRAIN
2. SOURCE
3. GATE
4. SOURCE

STYLE 12:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. NOT CONNECTED

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